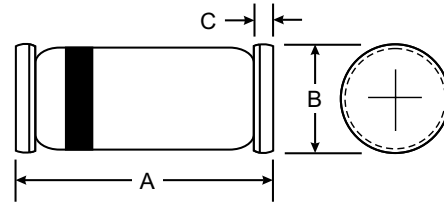


### Features

- Low forward rise voltage ( $V_F$ ) and satisfactory
- wave detection efficiency
- Small temperature coefficient of forward characteristic
- Extremely low reverse current  $I_R$



### Mechanical Data

- Case: SOD-80/LL34, Glass
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.05 grams (approx.)



LL34/ SOD-80		
Dim	Min	Max
A	3.30	3.70
B	1.30	1.60
C	0.28	0.50
All Dimensions in mm		

### Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Rating	Unit
Reverse Voltage (DC)	$V_R$	15	V
		30	
Peak Reverse Voltage	$V_{RM}$	15	V
		30	
Forward Current (DC)	$I_F$	30	mA
Peak Forward Current	$I_{FM}$	150	mA
Junction Temperature	$T_j$	125	$^\circ\text{C}$
Storage Temperature Range	$T_S$	-55 to +125	$^\circ\text{C}$

### Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Forward Voltage (DC)	$V_{F1}$	$I_F = 1\text{mA}$	-	-	0.4	V
	$V_{F2}$	$I_F = 30\text{mA}$	-	-	1	
Reverse Current (DC)	$I_R$	$V_R = 15\text{V}$	-	-	100	nA
		$V_R = 30\text{V}$	-	-	150	
Terminal Capacitance	$C_t$	$V_R = 1\text{V}, f = 1\text{MHz}$	-	1.3	-	pF
Reverse Recovery Time*	$t_{rr}$	$I_F = I_R = 10\text{mA}$ $I_{rr} = 1\text{mA}, R_L = 100\Omega$	-	1	-	ns
Detection Efficiency	$\eta$	$V_{in} = 3V_{(peak)}, f = 30\text{MHz}$ $R_L = 3.9\text{k}\Omega, C_L = 10\text{pF}$	-	60	-	%

Note: (1) Schottky barrier diode is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.

(2) Rated input / output frequency: 2,000MHz.

(3) \*:  $t_{rr}$  measuring instrument